



60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C
60V	10mΩ @ V _{GS} = 10V	89.5A
60 V	12mΩ @ V _{GS} = 4.5V	81.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- High-frequency switching
- Synchronous rectifications
- DC-DC converters

Features

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production— Ensures More Reliable and Robust End Application
- Low R_{DS(ON)}—Minimizes Power Losses
- Low Q_G—Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (<u>DMTH6009LPSQ</u>)

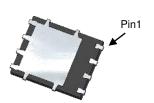
Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish—Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.097 grams (Approximate)

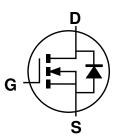
Site 1:



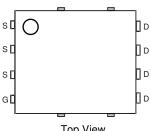
Top View



Bottom View



Internal Schematic



Top View Pin Configuration



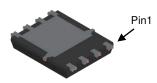
Site 2:

PowerDI5060-8/SWP (Type UX)

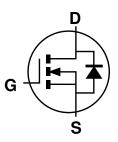
PowerDI5060-8



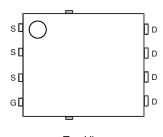




Bottom View



Internal Schematic



Top View Pin Configuration

Ordering Information (Note 4)

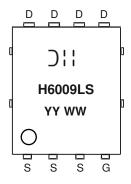
Part Number	Package	Packing		
Fait Number	Package	Qty.	Carrier	
DMTH6009LPS-13	PowerDI5060-8	2500	Tape & Reel	
DMTH6009LPS-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

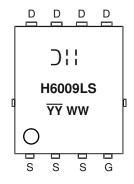
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information





];; = Manufacturer's Code Marking H6009LS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		Vgss	±16	V
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	11.76 8.3	А
Continuous Drain Current (Note 6)	T _C = +25°C T _C = +100°C	I _D	89.5 63.3	А
Maximum Continuous Body Diode Forward Current (Note 6)		Is	89	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	350	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	350	Α
Avalanche Current, L = 0.1mH		las	20.3	Α
Avalanche Energy, L = 0.1mH		Eas	20.6	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	53	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	136	W
Thermal Resistance, Junction to Case (Note 6)		R ₀ JC	1.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).



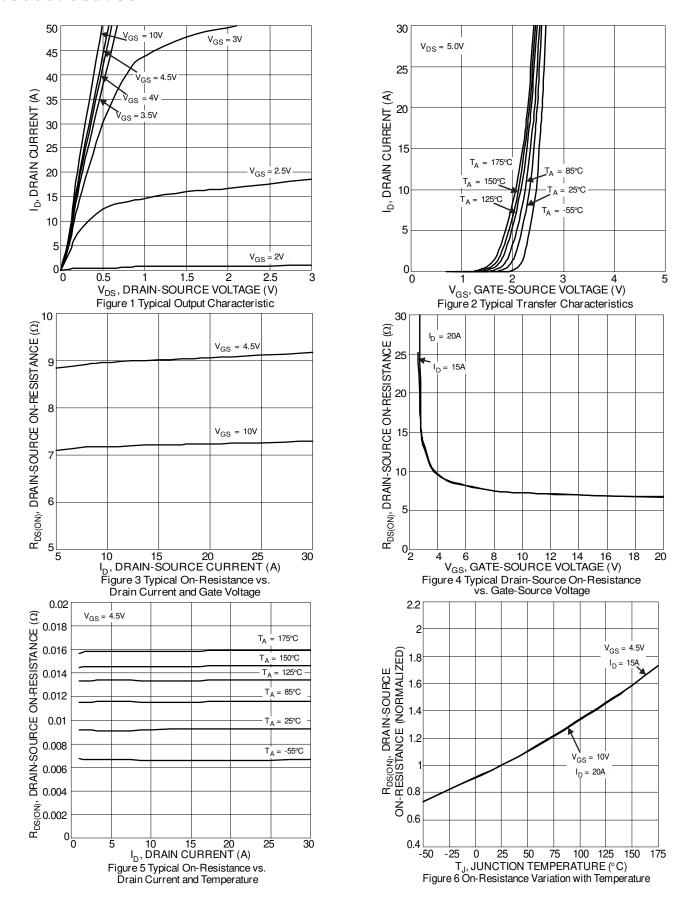
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60	_		V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 16V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.7	_	2	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Dagger		7.2	10	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Dialif-Source Off-nesistance	RDS(ON)		8.9	12	11122	$V_{GS} = 4.5V, I_D = 15A$	
Diode Forward Voltage	VsD	_	0.9	_	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	1925	_		V 20V V 0V	
Output Capacitance	Coss		438	_	pF	$V_{DS} = 30V$, $V_{GS} = 0V$, $f = 1MHz$	
Reverse Transfer Capacitance	Crss		41	_			
Gate Resistance	Rg		1.7	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (VGS = 10V)	Qg	_	33.5	_			
Total Gate Charge (V _{GS} = 4.5V)	Qg		15.6	_	nC	V _{DS} = 30V, I _D = 13.5A	
Gate-Source Charge	Qgs	_	4.7	_	IIC		
Gate-Drain Charge	Qgd	_	5.3	_			
Turn-On Delay Time	tD(ON)	_	4.5	_			
Turn-On Rise Time	t _R	_	8.6	_		$\begin{split} V_{DD} &= 30 V, V_{GS} = 10 V, \\ R_G &= 6 \Omega, I_D = 13.5 A \end{split}$	
Turn-Off Delay Time	tD(OFF)	_	35.9	_	ns		
Turn-Off Fall Time	tF	_	15.7	_			
Body Diode Reverse Recovery Time	trr	_	18.2	_	ns	L 10.50 di/dh 1000/	
Body Diode Reverse Recovery Charge	Qrr		33.1	_	nC	$I_F = 13.5A$, di/dt = 400A/ μ s	

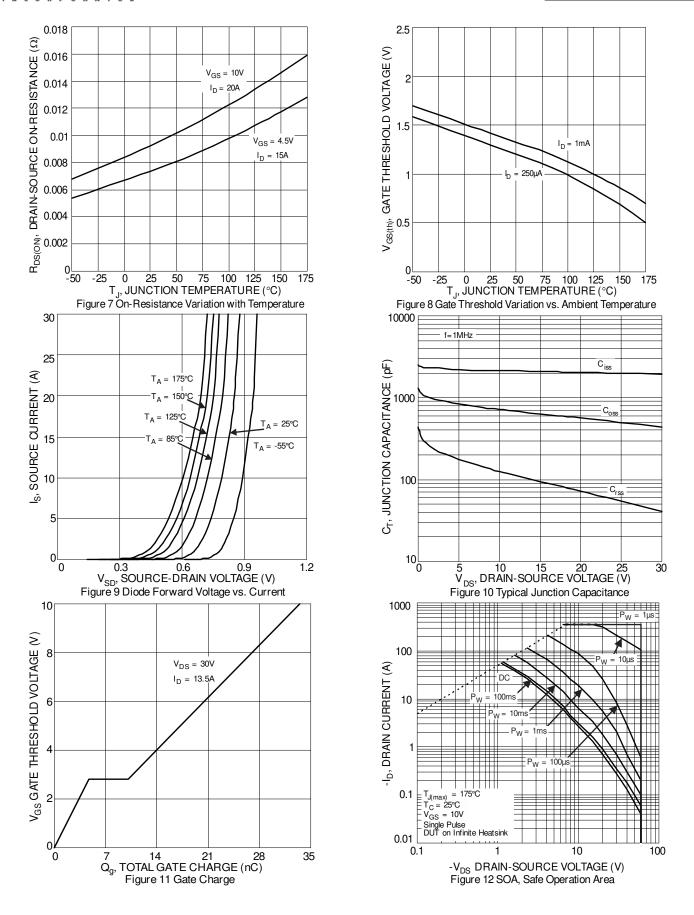
Notes:

^{7.} Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

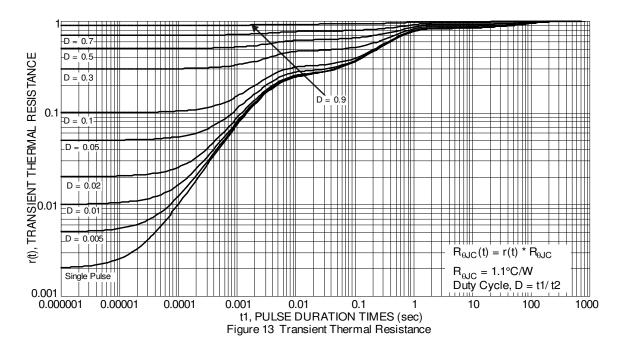












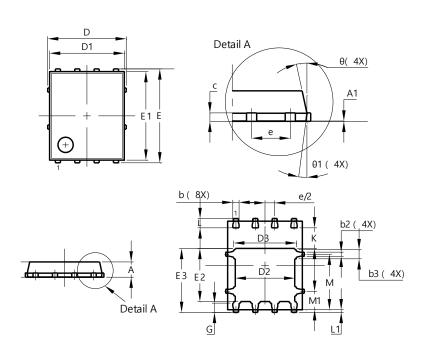


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

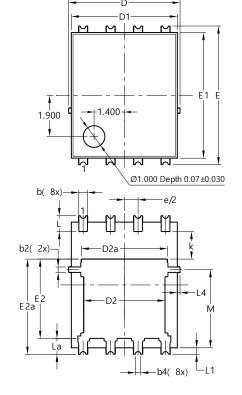
PowerDI5060-8

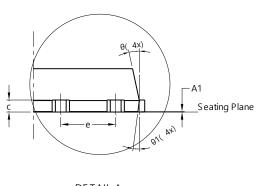


PowerDI5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A 1	0.00	0.05	-	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D		5.15 BSC	,	
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
Е	(6.15 BSC	;	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е	1.27 BSC			
G	0.51	0.71	0.61	
K	0.51	-	-	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
М	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
All Dimensions in mm				

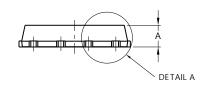
Site 2:

PowerDI5060-8/SWP (Type UX)





DETAIL A



PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	C).25REF	-	
С	0.230	0.330	0.277	
D		.15 BS()	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
Е	6	.40 BS0)	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0.050REF			
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

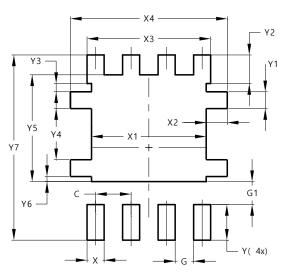


Suggested Pad Layout

 $Please\ see\ http://www.diodes.com/package-outlines.html\ for\ the\ latest\ version.$

Site 1:

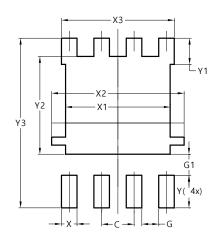
PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Υ	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value	
	(in mm)	
С	1.270	
G	0.660	
G1	0.820	
X	0.610	
X1	4.100	
X2	5.190	
Х3	4.420	
Υ	1.270	
Y1	1.020	
Y2	3.810	
Y3	6.610	



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